

## PH100-SI-HA-OD2-D0

Photodiode detector for laser power measurement up to 750 mW.



#### PRODUCT FAMILY KEY FEATURES

#### LARGE APERTURES

10 mm Ø for the silicon sensors

#### **3 VERSIONS**

- Silicon 350 1080 nm, up to 750 mW
- Silicon-UV 210 1080 nm, up to 38 mW
- Germanium 800 1650 nm, up to 500 mW

#### **CHOICE OF ATTENUATORS**

- OD0.3: 50% transmission (for PH100-SI<sup>UV</sup> only)
- OD1: 10% transmission
- OD2: 1% transmission

#### **HIGH ACCURACY**

The new PH100-SI-HA presents the lowest calibration uncertainty to date.

155 kHz

#### PRECISE CALIBRATION

Wavelength selection in 1 nm steps

#### SMART INTERFACE

Containing all the calibration data

#### **COMPATIBLE STAND**

STAND-D-233

### **SPECIFICATIONS**

Maximum average power <sup>1</sup>	750 mW
Noise equivalent power <sup>2</sup>	2 nW
Spectral range	630 - 1080 nm
Typical rise time	0.2 s
Power calibration uncertainty <sup>3</sup>	±4.0 % (630 - 899 nm) ±5.0 % (900 - 1009 nm) ±7.5 % (1010 - 1080 nm)
Peak sensitivity	980 nm

- 1. At 1064 nm, with attenuator. See curves for maximum power at other wavelengths.
- 2. At 980 nm. Nominal value. Actual value depends on environmental electromagnetic interference and wavelength.
- 3. With attenuator. See user manual for calibration uncertainty without attenuator.
- 4. See user manual for details.

Minimum repetition rate<sup>4</sup>

Dimensions

100 W/cm<sup>2</sup> Maximum average power density

### PHYSICAL CHARACTERISTICS

**MEASUREMENT CAPABILITIES** 

Aperture diameter	10 mm
Absorber	Si
Dimensions	38.1Ø x 36D mm

0.14 kg Weight

13.7 mm Distance to sensor face

ORDERING INFORMATION	
PH100-Si-HA-OD2-D0	202685
PH100-Si-HA-OD2-IDR-D0	203223
PH100-Si-HA-OD2-INT-D0	202786

Specifications are subject to change without notice. Refer to the user manual for complete specifications.

# **INTERESTED IN THIS PRODUCT?**



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